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Serial No.: 10/024,467

Filed: December 17, 2001

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Attorney's Docket No.: 10559-678001 / P13211

## Amendments to the Claims:

This listing of claims replaces all prior versions and listings of claims in the application:

## Listing of Claims:

- (Original) A method comprising:
  adjusting a threshold level of a radiation sensor in a radiation-measuring circuit; and obtaining an output signal based on radiation dose sensed by the radiation sensor.
- 2. (Original) The method of claim 1 further including exposing the radiation-measuring circuit to radiation.
- 3. (Currently Amended) The method of claim 1 wherein the radiation sensor includes a transistor, the method including and further comprising supplying a voltage between a body terminal and a source terminal of the transistor to adjust a body bias of the transistor radiation sensor.
- 4. (Original) The method of claim 3 including adjusting the body bias of the radiation-sensing transistor during exposure to radiation.
- 5. (Currently Amended) The method of claim 3 including adjusting the body bias of the radiation-sensing transistor using a voltage source that is external to the CMOS radiation-measuring circuit.
- 6. (Original) The method of claim 3 including adjusting the body bias of the radiation-sensing transistor using an integrated voltage source.



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7. - 8. (Canceled)

9. (Original) The apparatus of claim 7 wherein the radiation sensor forms part of a CMOS radiation-measuring circuit and the adjustable voltage source is integrated into the CMOS radiation-measuring circuit.

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10. (Currently Amended) The An apparatus of claim 7 comprising:

a radiation sensor with a threshold voltage;

an adjustable voltage source coupled to the radiation sensor to change the threshold

level of the radiation sensor;

a current mirror; and

an output load including a gate terminal and a drain terminal;

the radiation sensor having a source terminal coupled to a first side of the current mirror through a resistive element and coupled to the gate terminal of the output load; and the drain terminal of the output load coupled to a second side of the current mirror.

- 11. (Original) The apparatus of claim 10 wherein a state of the radiation sensor controls a state of the output load.
- 12. (Original) The apparatus of claim 10 wherein the resistive element includes a transistor.
- 13. (Original) The apparatus of claim 10 wherein the resistive element includes a resistor.
- 14. (Original) The apparatus of claim 10 wherein the current mirror includes pMOS transistors and each of the radiation sensor, the resistive element and the output load includes an nMOS transistor.

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15. (Original) The apparatus of claim 10 wherein the current mirror includes nMOS transistors and each of the radiation sensor, the resistive element, and the output load includes a pMOS transistor.

16. (Withdrawn) An apparatus comprising:

a first transistor to sense radiation;

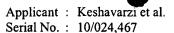
a load transistor having a gate coupled to an output of the first transistor and having an output to provide a signal whose digital state depends on a state of the first transistor; and a current mirror coupled to the first transistor and the load transistor.

17. (Withdrawn) The apparatus of claim 16 comprising an adjustable voltage source coupled to the first transistor to adjust a threshold voltage level of the first transistor.

18. (Withdrawn) The apparatus of claim 17 wherein the first transistor forms part of a radiation-measuring circuit and the adjustable voltage source is external to the radiation-measuring circuit.

- 19. (Withdrawn) The apparatus of claim 17 wherein the first transistor forms part of a radiation-measuring circuit and the adjustable voltage source is integrated into the radiation-measuring circuit.
- 20. (Withdrawn) The apparatus of claim 16 including a resistive element coupled to the output of the first transistor and a first side of the current mirror.
- 21. (Withdrawn) The apparatus of claim 20 wherein the resistive element includes a transistor.
- 22. (Withdrawn) The apparatus of claim 20 wherein the resistive element includes a resistor.

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23. (Withdrawn) The apparatus of claim 20 wherein the current mirror includes pMOS transistors and each of the radiation sensor, the resistive element and the output load includes an nMOS transistor.

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24. (Withdrawn) The apparatus of claim 20 wherein the current mirror includes nMOS transistors and each of the radiation sensor, the resistive element, and the output load includes a pMOS transistor.

25. (New) An apparatus comprising:

a CMOS radiation-measuring circuit;

a radiation sensor with a threshold voltage coupled to the CMOS radiation measuring circuit; and

an adjustable voltage source external to the CMOS radiation-measuring circuit to change the threshold level of the radiation sensor.

26. (New) An apparatus comprising:

a CMOS radiation-measuring circuit;

a radiation sensor with a threshold voltage coupled to the CMOS radiation measuring circuit; and

an adjustable voltage source integrated into the CMOS radiation-measuring circuit to change the threshold level of the radiation sensor.

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